EECS 217

Lecture 19: Mason's U Function/Examples

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Mason's Invariant U Function

• \bullet Mason discovered the function U given by

$$
U = \frac{|k_{21} - k_{12}|^2}{4(\Re(k_{11})\Re(k_{22}) - \Re(k_{12})\Re(k_{21}))}
$$

•**•** For the hybrid matrix formulation $(H$ or $G)$, the U function is given by

$$
U = \frac{|k_{21} + k_{12}|^2}{4(\Re(k_{11})\Re(k_{22}) + \Re(k_{12})\Re(k_{21}))}
$$

- •• where k_{ij} are the two-port Y or Z parameters.
- • This function is invariant under lossless reciprocal embeddings. Stated differently, any two-port can be *embedded* into a lossless and reciprocal circuit and the resulting two-port will have the same U function.
- \bullet This is ^a very important property, because this invariant property does not dependon any lossless matching circuitry that we employ before or after the two-port, orany lossless feedback. What does U signify?

Properties of ^U

- \bullet The invariant property is shown above. The U of the original two-port is the same as U_a of the overall two-port when a four port lossless reciprocal four-port is added.
- \bullet **•** The U function has several important properties:
	- 1. If $U>1$, the two-port is active. Otherwise, if $U\leq 1$, the two-port is passive.
	- 2. $\ U$ is the maximum unilateral power gain of a device under a lossless reciprocal embedding.
	- 3. $\ U$ is the maximum gain of a three-terminal device regardless of the common terminal.

Invariance of U

• With regards to the previous diagram, any lossless reciprocal embedding can be seen as an interconnection of the original two-port to ^a four-port, with the followingblock admittance matrix

$$
\begin{pmatrix} I_a \\ -I \end{pmatrix} = \begin{pmatrix} Y_{11}^0 & Y_{12}^0 \\ Y_{21}^0 & Y_{22}^0 \end{pmatrix} \begin{pmatrix} V_a \\ V \end{pmatrix}
$$

• \bullet Note that Y_{ij} is a 2×2 imaginary symmetric sub-matrix

$$
Y_{jk}^0 = jB_{jk}
$$

$$
B_{jk} = B_{kj}^T
$$

•Since $I = YV$, we can solve for V from the second equation

$$
-I = Y_{21}^{0}V_a + Y_{22}^{0}V = -YV
$$

$$
V = -(Y + Y_{22}^{0})^{-1}Y_{21}^{0}V_a
$$

U Invariance (cont)

 \bullet From the first equation we have the composite two-port matrix

$$
I_a = (Y_{11}^0 - Y_{12}^0 (Y + Y_{22}^0)^{-1} Y_{21}^0) V_a = Y_a V_a
$$

 \bullet \bullet By definition, the U function is given by

$$
U = \frac{\det(Y_a - Y_a^T)}{\det(Y_a + Y_a^*)}
$$

 \bullet • Note that Y_a can be written as

$$
Y_a = jB_{11} - jB_{12}(Y + jB_{22})^{-1}jB_{12}^T
$$

$$
Y_a = jB_{11} + B_{12}(Y + jB_{22})^{-1}B_{12}^T
$$

 \bullet Focus on the denominator of U

$$
Y_a + Y_a^* = B_{12}(W^{-1} + (W^*)^{-1})B_{12}^T
$$

 \bullet • where $W = Y + Y_{22}^0 = Y + jB_{22}$.

Invariance (cont)

 \bullet ● Factoring W^{-1} from the left and $(W^*)^{-1}$ from the right, we have

$$
= B_{12}W^{-1}(W^* + W)(W^*)^{-1}B_{12}^T
$$

• But $W + W^* = Y + Y^*$ resulting in

$$
Y_a + Y_a^* = B_{12}W^{-1}(Y + Y^*)(W^*)^{-1}B_{12}^T
$$

 \bullet In ^a like manner, one can show that

$$
Y_a - Y_a^T = B_{12}W^{-1}(Y^T - Y)(W^*)^{-1}B_{12}^T
$$

 \bullet Taking the determinants and ratios

$$
\begin{aligned} \det(Y_a + Y_a^*) &= \frac{(\det B_{12})^2 \det(Y + Y^*)}{(\det W)^2} \\ \det(Y_a - Y_a^T) &= \frac{(\det B_{12})^2 \det(Y^T - Y)}{(\det W)^2} \\ U &= \frac{\det(Y_a - Y_a^T)}{\det(Y_a + Y_a^*)} = \frac{\det(Y - Y^T)}{\det(Y + Y^*)} \\ \end{aligned}
$$

Maximum Unilateral Gain

 \bullet **Consider the above feedback structure where** y_f and y_α We can derive the overall two-port equations by ^a cascade connection followed by α are lossless reactances. ^a shunt connection of two-ports

$$
Y_a = \frac{y_\alpha}{y_\alpha + y_{22}} \begin{bmatrix} y_{11} + \Delta_y/y_\alpha & y_{12} \\ y_{21} & y_{22} \end{bmatrix} + \begin{bmatrix} y_f & -y_f \\ -y_f & y_f \end{bmatrix}
$$

Unilaterization

 \bullet To unilaterize the device, we select

$$
y_f = \frac{y_{12}y_{\alpha}}{y_{22} + y_{\alpha}}
$$

 \bullet \bullet We can solve for b_{α} and b_f

$$
b_f=\Im(y_{12})-\frac{\Re(y_{12})}{\Re(y_{22})}\Im(y_{22})
$$

$$
b_{\alpha} = b_f \frac{\Re(y_{22})}{\Re(y_{12})}
$$

 \bullet It can be shown that the overall Y_a matrix is given by

$$
Y_a = \frac{j \Im(y_{22}^* y_{12})}{y_{12} \Re(y_{22})} \begin{bmatrix} y_{11} + y_{12} - j \frac{\Delta_y \Re(y_{12})}{\Im(y_{22}^* y_{12})} & 0\\ y_{21} - y_{12} & y_{22} + y_{12} \end{bmatrix}
$$

Unilaterized Two-Port

• The two-port equivalent circuit under unilaterization is shown above. Notice nowthat the maximum power gain of this circuit is given by

$$
G_{U,max} = \frac{|Y_{a_{21}}|^2}{4\Re(Y_{a_{11}})\Re(Y_{a_{22}})} = U_a
$$

- \bullet Thus we can attribute physical significance to U_a as the maximum unilateral gain. Furthermore, due to the invariance of $U,\,U_a=U$ for the original two-port network.
- •**It's important to note that** *any* **unilaterization scheme will yield the same maximum** power! Thus U is a good metric for the device.

Gain Plots

- • \bullet U is often used as a metric for a two-port device. It represents the maximum gain that the device can deliver if we use lossless reciprocal embeddings to unilaterizethe device. U is also a good metric for characterizing a three terminal device with a common-terminal, such as ^a transistor.
- • \bullet U is invariant to the common terminal, so a common-gate amplifier has the same U as a common-source amplifier.
- •In the figure above, the device G_{MSG} is plotted for low frequencies where $K < 1$.
At the breakpoint $K > 1$ and the device is upsenditionally stable and thus G At the breakpoint, $K > 1$ and the device is unconditionally stable and thus G_{max} is plotted. Note that the U curve is always larger than G_{max} but both curves cross
... In the detailed in the fact of the state o $0\,\mathrm{dB}$ together. At this point, the f_{max} of the device, the two-port becomes passive.

Stability Examples

• ^A simple equivalent circuit for ^a FET without any feedback is of course absolutely stable if the resistors of the model are positive. The Z matrix for the circuit is given by

$$
Z = \begin{bmatrix} \frac{1}{j\omega C_{gs}} & 0\\ \frac{-g_m r_o}{j\omega C_{gs}} & r_o \end{bmatrix}
$$

•Since $Z_{12}=0$, the stability factor $K=\infty$

$$
K = \frac{2\Re(Z_{11})\Re(Z_{22}) - \Re(Z_{12}Z_{21})}{|Z_{12}Z_{21}|}
$$

Inductive Degeneration

•● Although $Z_{12}\approx0$ for a FET at low frequency, the input impedance is purely capacitive. To introduce ^a real component, inductive degeneration is commonlyemployed. The Z matrix for the inductor is simply

$$
Z=j\omega L_s\begin{bmatrix}1&1\\1&1\end{bmatrix}
$$

•• Adding the Z matrix (due to series connection)

$$
Z = \begin{bmatrix} j\omega L_s + \frac{1}{j\omega C_{gs}} & j\omega L_s \\ j\omega L_s - \frac{g_m r_o}{j\omega C_{gs}} & r_o + j\omega L_s \end{bmatrix}
$$

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Inductive Degen (cont)

•**•** This feedback introduces a Z_{12} and thus the stability must be carefully examined

$$
K = \frac{2 \cdot 0 \cdot r_o - \left(-\omega^2 L_s^2 - \frac{g_m L_s r_o}{C_{gs}}\right)}{\omega^2 L_s^2 + \frac{g_m r_o L_s}{C_{gs}}} = 1
$$

- \bullet We see that this circuit is unconditionally stable. More importantly, the stabilityfactor is frequency independent. In reality parasitics can destabilize the transistor.
- •The maximum gain is thus given by

$$
G_{max} = \left| \frac{Z_{21}}{Z_{12}} \right| \left(K - \sqrt{K^2 - 1} \right) = \left| \frac{Z_{21}}{Z_{12}} \right|
$$

$$
=\frac{\omega L_s + \frac{g_m r_o}{\omega C_{gs}}}{\omega L_s} = 1 + \frac{g_m r_o}{\omega^2 L_s C_{gs}}
$$

$$
=1+\left(\frac{\omega_T}{\omega_0}\right)^2\left(\frac{r_o}{\omega_T L_s}\right)
$$

•It's easy to show that the synthesize real input resistance is $\omega_T L_s$, and so the last term is the ratio of r_o/R_S under matched conditions.

Capacitive Degeneration

 \bullet • The Z matrix for capacitive degeneration is given by

$$
Z = \begin{bmatrix} \frac{1}{j\omega C_s} + \frac{1}{j\omega C_{gs}} & \frac{1}{j\omega C_s} \\ \frac{1}{j\omega C_s} - \frac{g_m r_o}{j\omega C_{gs}} & r_o + \frac{1}{j\omega C_s} \end{bmatrix}
$$

•The stability factor is given by

$$
K = \frac{2 \cdot 0 \cdot r_o - \left(\frac{g_m r_o}{\omega^2 C_s C_{gs}} - \frac{1}{\omega^2 C_s^2}\right)}{\left|\frac{g_m r_o}{\omega^2 C_s C_{gs}} - \frac{1}{\omega^2 C_s^2}\right|}
$$

 \bullet Note this is simply

$$
K = \frac{-a+b}{|a-b|} = \begin{cases} \frac{b-a}{a-b} < 0 & a > b \\ \frac{b-a}{b-a} & = 1 & b < a \end{cases}
$$

 \bullet The condition for stability is therefore

$$
\frac{g_m r_o}{C_{gs}} > \frac{1}{C_s}
$$

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∩

Range of ^K

- \bullet So far we have dealt with $K > 0$. Suppose that $|\Delta| > 1$. We know that for $0 < K < 1$ the two-port is conditionally stable. In other words, the stability circle
intersects with the unit sirele with the everlen (usually) corresponding to the intersects with the unit circle with the overlap (usually) corresponding to theunstable region. Instability can also occur if $K>1$ and $|\Delta|>1,$ but this is less
services (seevie with ED) common (occurs with FB).
- \bullet On the other hand, if $-1 < K < 0$, one can show graphically that the entire unit
originals an the Smith Chart is unatable. In other words, the otability circle does not circle on the Smith Chart is unstable. In other words, the stability circle does not intersect with the unit circle or the instability circle contains the entire circle.

Resistive Degeneration

 \bullet Resistive degeneration is commonly employed to stabilize the bias point of ^atransistor. The Z matrix is given by

$$
Z = \begin{bmatrix} R_s + \frac{1}{j\omega C_{gs}} & R_s \\ R_s - \frac{g_m r_o}{j\omega C_{gs}} & r_o + R_s \end{bmatrix}
$$

 \bullet • The K factor is computed as before

$$
K = \frac{2R_s(r_o + R_s) - R_s^2}{R_s \sqrt{R_s^2 + \frac{g_m^2 r_o^2}{\omega^2 C_{gs}^2}}}
$$

•At low frequencies, we have

$$
K = \frac{2r_o + R_s}{\frac{g_m r_o}{\omega C_{gs}}} \approx \frac{2\omega C_{gs}}{g_m} = \frac{2\omega}{\omega_T} < 1
$$

Shunt Feedback

 \bullet **Shunt feedback is a common broadband matching approach. Now working with** the Y matrix of the transistor (simplified as before)

$$
Y_{fet} = \begin{bmatrix} j\omega C_{gs} & 0\\ g_m & G_o + j\omega C_{ds} \end{bmatrix}
$$

•• The feedback element has a Y matrix

$$
Y_f = G_f \begin{bmatrix} +1 & -1 \\ -1 & +1 \end{bmatrix}
$$

 \bullet And thus the overall amplifier

$$
Y = \begin{bmatrix} G_f + j\omega C_{gs} & -G_f \\ g_m - G_f & G_f + G_o + j\omega C_{ds} \end{bmatrix}
$$

Shunt Feedback (cont)

•The stability factor for the shunt feedback amplifier is given by

$$
K = \frac{2G_f(G_o + G_f) - G_f(G_f - g_m)}{G_f|g_m - G_f|}
$$

•**Suppose that** $g_m R_f > 1$

$$
= \frac{g_m + G_f}{g_m - G_f} = \frac{g_m R_f + 1}{g_m R_f - 1} > 1
$$

 \bullet The choice of R_f and g_m is governed by the current consumption, power gain, and impedance matching. For ^a bi-conjugate match

$$
G_{max} = \left| \frac{Y_{21}}{Y_{12}} \right| \left(K - \sqrt{K^2 - 1} \right)
$$

$$
=\frac{g_m-G_f}{G_f}\left(\left(\frac{g_mR_f+1}{g_mR_f-1}\right)-\sqrt{\left(\frac{g_mR_f+1}{g_mR_f-1}\right)^2-1}\right)=\left(1-\sqrt{g_mR_F}\right)^2
$$

Shunt Feedback Input Admittance

 \bullet The input admittance is calculated as follows

$$
Y_{in} = Y_{11} - \frac{Y_{12}Y_{21}}{Y_{22} + Y_L}
$$

$$
= j\omega C_{gs} + G_f - \frac{-G_f(g_m - G_f)}{G_o + G_f + G_L + j\omega C_{ds}}
$$

$$
= j\omega C_{gs} + G_f + \frac{G_f(g_m - G_f)(G_o + G_f + G_L - j\omega C_{ds})}{(G_o + G_f + G_L)^2 + \omega^2 C_{ds}^2}
$$

 \bullet At lower frequencies, $\omega < \frac{1}{C_{de}R_1}$ $C_{ds}R_f||R_L$ $_{L}^{-}$ we have (neglecting G_{o})

$$
\Re(Y_{in}) = G_f + \frac{G_f(g_m - G_f)}{G_f + G_L}
$$

$$
= \frac{1 + g_m R_L}{R_F + R_L}
$$

$$
\Im(Y_{in}) = \omega \left(C_{gs} - \frac{C_{ds}}{1 + \frac{R_f}{R_L}} \right)
$$

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